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# 20 V, 7.0 A, Low V<sub>CE(sat)</sub> **PNP Transistor**

ON Semiconductor's e<sup>2</sup>PowerEdge family of low V<sub>CE(sat)</sub> transistors are miniature surface mount devices featuring ultra low saturation voltage (V<sub>CE(sat)</sub>) and high current gain capability. These are designed for use in low voltage, high speed switching applications where affordable efficient energy control is important.

Typical applications are DC-DC converters and power management in portable and battery powered products such as cellular and cordless phones, PDAs, computers, printers, digital cameras and MP3 players. Other applications are low voltage motor controls in mass storage products such as disc drives and tape drives. In the automotive industry they can be used in air bag deployment and in the instrument cluster. The high current gain allows e<sup>2</sup>PowerEdge devices to be driven directly from PMU's control outputs, and the Linear Gain (Beta) makes them ideal components in analog amplifiers.

• This is a Pb-Free Device

### **MAXIMUM RATINGS** $(T_A = 25^{\circ}C)$

Rating	Symbol	Max	Unit	
Collector-Emitter Voltage	V <sub>CEO</sub>	-20	Vdc	
Collector-Base Voltage	V <sub>CBO</sub>	-20	Vdc	
Emitter-Base Voltage	V <sub>EBO</sub>	-7.0	Vdc	
Collector Current - Continuous	I <sub>C</sub>	-5.0	Adc	
Collector Current - Peak	I <sub>CM</sub>	-7.0	Α	
Electrostatic Discharge	ESD	HBM Class 3B MM Class C		

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit	
Total Device Dissipation, T <sub>A</sub> = 25°C Derate above 25°C (Note 1)	P <sub>D</sub>	875 7.0	mW mW/°C	
Thermal Resistance, Junction-to-Ambient (Note 1)	$R_{\theta JA}$	143	°C/W	
Total Device Dissipation, T <sub>A</sub> = 25°C Derate above 25°C (Note 2)	P <sub>D</sub>	1.5 11.8	W mW/°C	
Thermal Resistance, Junction-to-Ambient (Note 2)	$R_{ heta JA}$	85	°C/W	
Thermal Resistance, Junction-to-Lead #1 (Note 2)	$R_{ heta JL}$	23	°C/W	
Total Device Dissipation (Single Pulse < 10 sec) (Notes 2, 3)	P <sub>Dsingle</sub>	3.0	W	
Junction and Storage Temperature Range	T <sub>J</sub> , T <sub>stg</sub>	–55 to +150	°C	
Operating Case Temperature (Note 1)	T <sub>C</sub>	-55 to +125	°C	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1

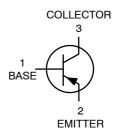
- FR-4 @ 100 mm<sup>2</sup>, 1 oz copper traces.
   FR-4 @ 500 mm<sup>2</sup>, 1 oz copper traces.
- 3. Thermal response.



# ON Semiconductor®

http://onsemi.com

# -20 VOLTS **7.0 AMPS** PNP LOW $V_{CE(sat)}$ TRANSISTOR EQUIVALENT $R_{DS(on)}$ 50 m $\Omega$





**WDFN3** CASE 506AU

### MARKING DIAGRAM



VC = Specific Device Code

= Date Code

= Pb-Free Package

### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>	
NSS20500UW3T2G	WDFN3 (Pb-Free)	3000/ Tape & Reel	
NSS20500UW3TBG	WDFN3 (Pb-Free)	3000/ Tape & Reel	

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Typical	Max	Unit
OFF CHARACTERISTICS	, 1		1		
Collector – Emitter Breakdown Voltage $(I_C = -10 \text{ mAdc}, I_B = 0)$	V <sub>(BR)</sub> CEO	-20	-	-	Vdc
Collector – Base Breakdown Voltage $(I_C = -0.1 \text{ mAdc}, I_E = 0)$	V <sub>(BR)</sub> CBO	-20	-	-	Vdc
Emitter – Base Breakdown Voltage $(I_E = -0.1 \text{ mAdc}, I_C = 0)$	V <sub>(BR)EBO</sub>	-7.0	-	_	Vdc
Collector Cutoff Current $(V_{CB} = -20 \text{ Vdc}, I_E = 0)$	I <sub>CBO</sub>	_	-	-0.1	μAdc
Emitter Cutoff Current (V <sub>EB</sub> = -7.0 Vdc)	I <sub>EBO</sub>	_	-	-0.1	μAdc
ON CHARACTERISTICS	<u>.</u>				
DC Current Gain (Note 4) $ \begin{aligned} &(I_C = -10 \text{ mA}, \ V_{CE} = -2.0 \text{ V}) \\ &(I_C = -500 \text{ mA}, \ V_{CE} = -2.0 \text{ V}) \\ &(I_C = -1.0 \text{ A}, \ V_{CE} = -2.0 \text{ V}) \\ &(I_C = -2.0 \text{ A}, \ V_{CE} = -2.0 \text{ V}) \\ &(I_C = -3.0 \text{ A}, \ V_{CE} = -2.0 \text{ V}) \end{aligned} $	h <sub>FE</sub>	250 250 220 200 180	- 300 300 250	- - - -	
Collector – Emitter Saturation Voltage (Note 4) ( $I_C = -0.1 \text{ A}$ , $I_B = -0.010 \text{ A}$ ) (Note 5) ( $I_C = -1.0 \text{ A}$ , $I_B = -0.100 \text{ A}$ ) ( $I_C = -1.0 \text{ A}$ , $I_B = -0.010 \text{ A}$ ) ( $I_C = -2.0 \text{ A}$ , $I_B = -0.020 \text{ A}$ ) ( $I_C = -3.0 \text{ A}$ , $I_B = -0.030 \text{ A}$ ) ( $I_C = -4.0 \text{ A}$ , $I_B = -0.400 \text{ A}$ )	V <sub>CE(sat)</sub>	- - - -	-0.010 -0.050 -0.080 -0.150 -0.200 -0.270	-0.015 -0.070 -0.100 -0.170 -0.240 -0.260	V
Base – Emitter Saturation Voltage (Note 4) $(I_C = -1.0 \text{ A}, I_B = -0.01 \text{ A})$	V <sub>BE(sat)</sub>	-	0.76	-0.900	V
Base – Emitter Turn–on Voltage (Note 4) $(I_C = -2.0 \text{ A}, V_{CE} = -3.0 \text{ V})$	V <sub>BE(on)</sub>	-	0.80	-0.900	V
Cutoff Frequency ( $I_C = -100 \text{ mA}$ , $V_{CE} = -5.0 \text{ V}$ , $f = 100 \text{ MHz}$ )	f <sub>T</sub>	100	-	_	MHz
Input Capacitance (V <sub>EB</sub> = -0.5 V, f = 1.0 MHz)	Cibo	-		475	pF
Output Capacitance (V <sub>CB</sub> = -3.0 V, f = 1.0 MHz)	Cobo	=		180	pF
SWITCHING CHARACTERISTICS					
Delay ( $V_{CC} = -15 \text{ V}, I_C = 750 \text{ mA}, I_{B1} = 15 \text{ mA}$ )	t <sub>d</sub>	-	_	75	ns
Rise ( $V_{CC} = -15 \text{ V}, I_C = 750 \text{ mA}, I_{B1} = 15 \text{ mA}$ )	t <sub>r</sub>	-	_	160	ns
Storage ( $V_{CC} = -15 \text{ V}, I_C = 750 \text{ mA}, I_{B1} = 15 \text{ mA}$ )	t <sub>s</sub>	-	_	350	ns
Fall ( $V_{CC} = -15 \text{ V}, I_C = 750 \text{ mA}, I_{B1} = 15 \text{ mA}$ )	t <sub>f</sub>	-	-	160	ns

Pulsed Condition: Pulse Width = 300 μsec, Duty Cycle ≤ 2%.
 Guaranteed by design but not tested.

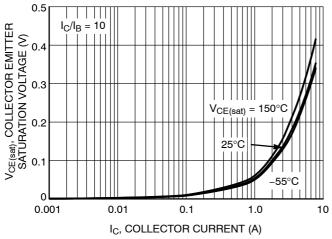
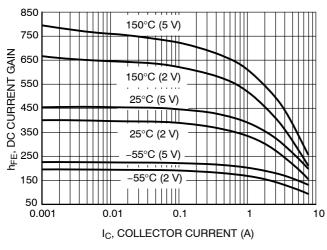


Figure 1. Collector Emitter Saturation Voltage vs. Collector Current

Figure 2. Collector Emitter Saturation Voltage vs. Collector Current



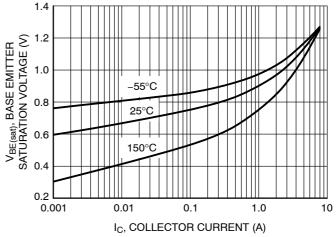
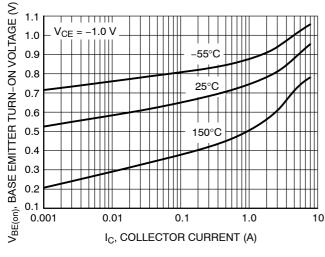


Figure 3. DC Current Gain vs. Collector Current

Figure 4. Base Emitter Saturation Voltage vs.
Collector Current



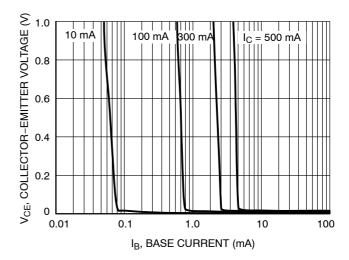


Figure 5. Base Emitter Turn-On Voltage vs. Collector Current

Figure 6. Saturation Region

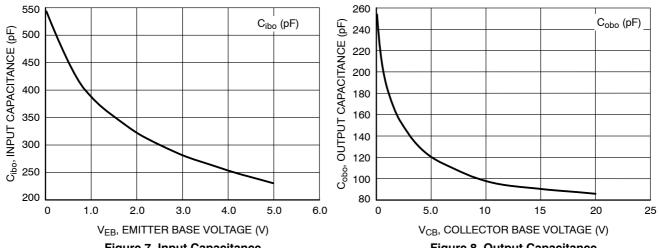


Figure 7. Input Capacitance

Figure 8. Output Capacitance

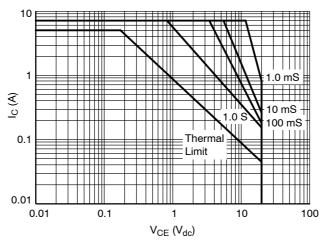
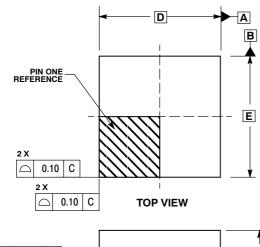
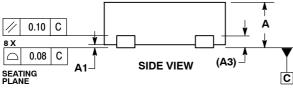


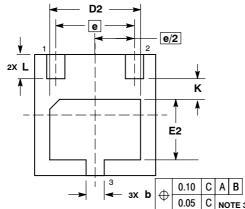
Figure 9. PNP Safe Operating Area

### PACKAGE DIMENSIONS

### WDFN3 CASE 506AU **ISSUE O**







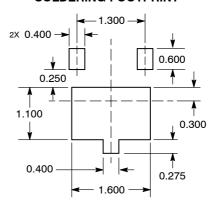
**BOTTOM VIEW** 

#### NOTES

- DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
- CONTROLLING DIMENSION: MILLIMETERS.
  DIMENSION & APPLIES TO PLATED TERMINAL AND IS
  MEASURED BETWEEN 0.25 AND 0.30 MM FROM TERMINAL.
  COPLANARITY APPLIES TO THE EXPOSED PAD AS WELL AS
- THE TERMINALS

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	0.70	0.75	0.80	0.028	0.030	0.031
A1	0.00		0.05	0.000		0.002
А3	0.20 REF			0.008 REF		
b	0.25	0.30	0.35	0.010	0.012	0.014
D	2.00 BSC			0.079 BSC		
D2	1.40	1.50	1.60	0.055	0.059	0.063
E	2.00 BSC			0.079 BSC		
E2	0.90	1.00	1.10	0.035	0.039	0.043
е	1.30 BSC			0.051 BSC		
K	0.35 REF			0.014 REF		
L	0.35	0.40	0.45	0.014	0.016	0.018

### **SOLDERING FOOTPRINT\***



\*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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